

## **Submicrometer optical characterization of the grain boundary of optically active Cr<sup>3+</sup> doped polycrystalline Al<sub>2</sub>O<sub>3</sub> by near-field spectroscopy**

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### **ABSTRACT**

Near-field fluorescent spectroscopy was used to characterize the grain boundary of Cr-doped polycrystalline alumina. The results show that the peak widths in near-field spectra are narrower than in spectra obtained by conventional microspectrometry, and this is attributed to the difference in spatial resolution of the two methods. The R-line peaks of Cr<sup>3+</sup> fluorescence were observed to shift to a lower wavelength at the grain boundary compared to the bulk crystal, which is attributed to stress relief at the crystal boundary. This peak shift at the boundary decreases as a function of the time a polycrystal is annealed at 1700 °C.